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BT137-800 4Q Triac

12 June 2014

Product data sheet

General description 1.

Planar passivated four quadrant triac in a SOT78 plastic package intended for use in bidirectional switching and phase control applications.

2. Features and benefits

- High blocking voltage capability
- Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability •
- Triggering in all four quadrants

Applications 3.

- General purpose motor control •
- General purpose switching

Quick reference data 4.

•

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4; Fig. 5}$ | - | - | 65 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 102 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 8 | A |
| Static chara | acteristics | | , i | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$ | - | 5 | 35 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$ | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 11 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 30 | 70 | mA |







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5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | |
| mb | T2 | mounting base; main terminal 2 | | |
| | | | TO-220AB (SOT78) | |

6. Ordering information

| Table 3. Ordering information | | | | | | |
|-------------------------------|----------|--|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BT137-800 | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | | |

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Мах | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 102 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3 | - | 8 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5 | - | 65 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 71 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 21 | A ² s |
| dI _T /dt | rate of rise of on-state current | I_T = 12 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G+ | - | 50 | A/µs |
| | | I_T = 12 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2+ G- | - | 50 | A/µs |
| | | I_T = 12 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2- G- | - | 50 | A/µs |
| | | I_T = 12 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs; T2- G+ | - | 10 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

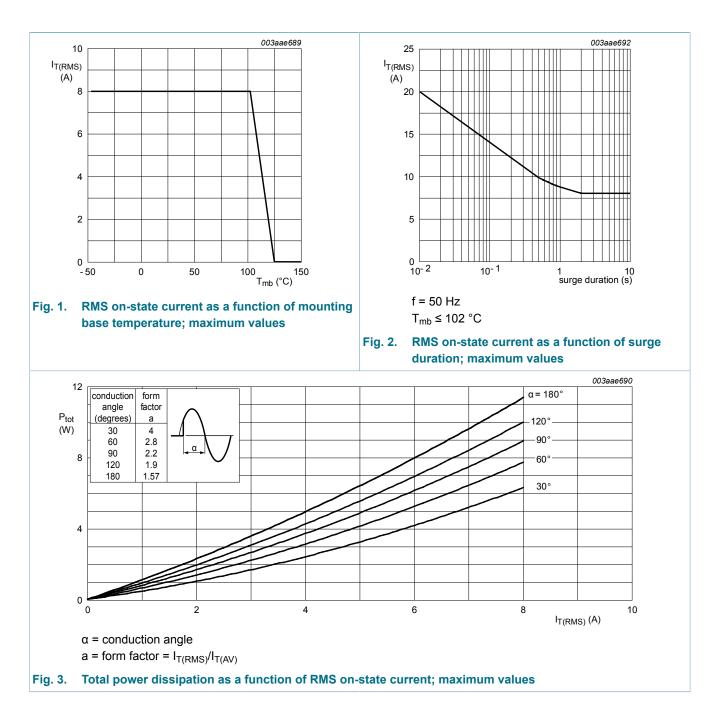


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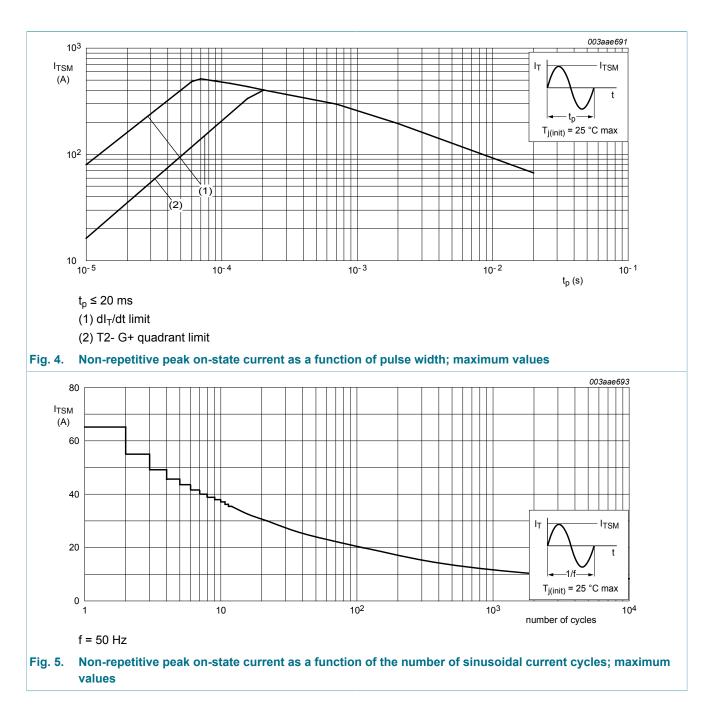


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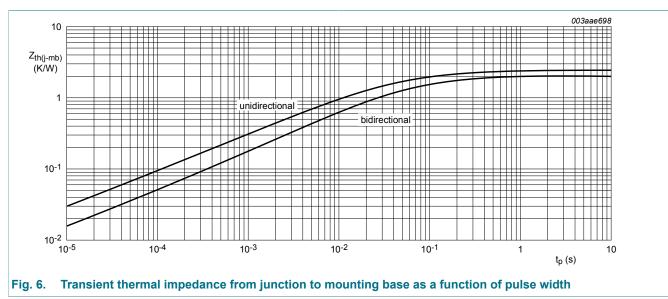


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8. Thermal characteristics

| Table 5. The | rmal characteristics | | | | | |
|-----------------------|---|---------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | half cycle; Fig. 6 | - | - | 2.4 | K/W |
| | | full cycle; <u>Fig. 6</u> | - | - | 2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |





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9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|------|-----|------|------|
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 35 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$ | - | 8 | 35 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$ | - | 11 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 30 | 70 | mA |
| ΙL | latching current | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_j = 25 \text{ °C}; \text{ Fig. 8}$ | - | 7 | 30 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$ | - | 16 | 45 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | 5 | 30 | mA |
| | | V_D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 45 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 5 | 20 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.3 | 1.65 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 800 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic ch | aracteristics | · · · · · | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 100 | 250 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_D = 400 V; T _j = 95 °C; dI _{com} /dt = 3.6 A/ ms; I _T = 8 A; gate open circuit | - | 20 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | I_{TM} = 12 A; V_D = 800 V; I_G = 0.1 A; dI_G/dt = 5 A/µs | - | 2 | - | μs |

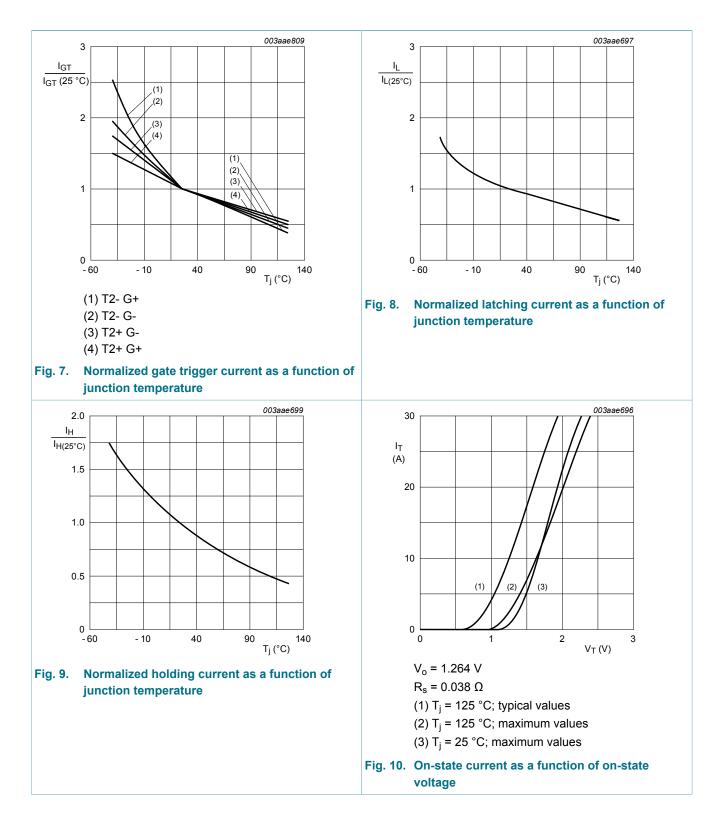


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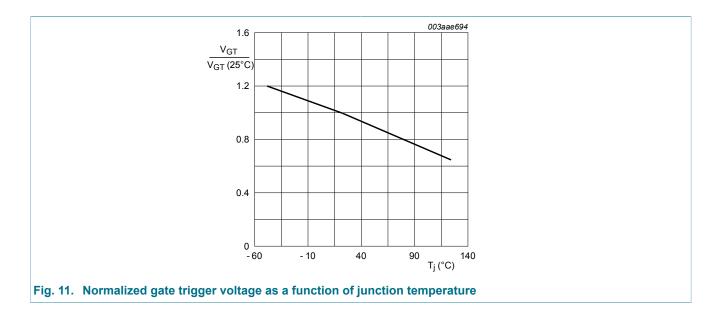
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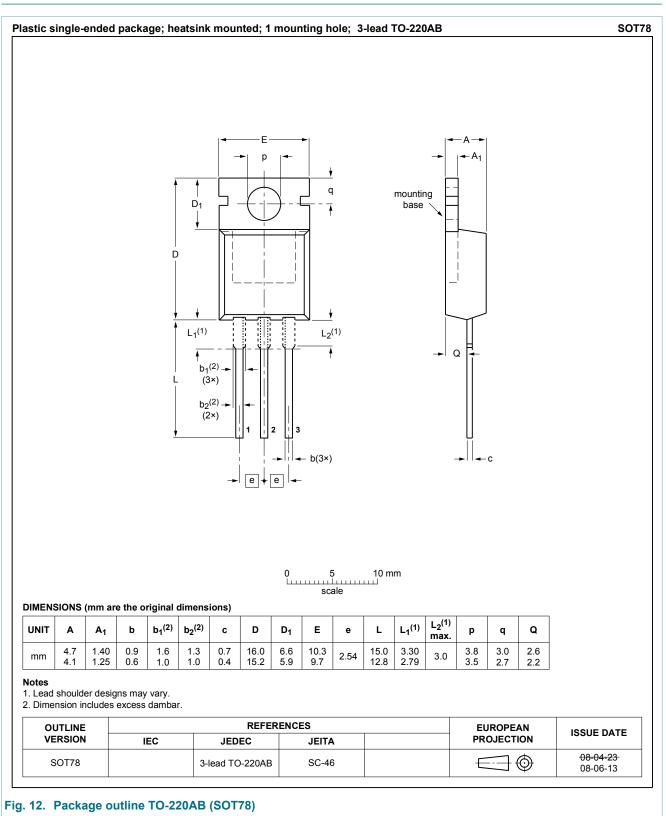
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10. Package outline



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11. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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